

IGBT in TO-264

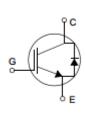
Features

- ■1200V 40A,VCE(sat)(typ.) = 2.0 V@40A
- Higher system efficiency
- Soft current turn-off waveforms



- Case: TO-264 (plastic package). Lead free; RoHS compliant
- Molding Compound Flammability Rating: UL 94 V-0
- **Terminals:** High temperature soldering guaranteed: 260 °C/10 sec. at terminals





Benefits

- High Efficiency for Motor Control
- Rugged Performance
- Excellent Current Sharing in Parallel Operation

Applications

CREATEK's IGBTs offer lower losses and higher energy for application such as motor drive ,UPS, inverter and other soft switching applications.

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
V_{CES}	Collector-Emitter Voltage	1200	V
V_{GES}	Gate-Emitter Voltage	±30	V
Ic	Continuous Collector Current (T _C =25 °C)	80	Α
ic	Continuous Collector Current (T _C =100°C)	40	Α
I _{CM}	Pulsed Collector Current (Note 1)	360	Α
l _F	Diode Continuous Forward Current (T _C =100 ℃)	40	А
I _{FM}	Diode Maximum Forward Current (Note 1)	400	Α
t _{sc}	Short Circuit Withstand Time	10	us
P _D	Maximum Power Dissipation (T _C =25 ℃)	500	W
	Maximum Power Dissipation (T _C =100℃)	200	W
TJ	Operating Junction Temperature Range	-55 to +150	$^{\circ}$
T _{STG}	Storage Temperature Range	-55 to +150	$^{\circ}$

Thermal Characteristics

Symbol	Parameter	Max.	Units
R _{th j-c}	Thermal Resistance, Junction to case for IGBT	0.25	°C/ W
R _{th j-c}	Thermal Resistance, Junction to case for Diode	0.7	°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient	25	°C/W

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Electrical Characteristics (TC=25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
BV _{CES}	Collector-Emitter Breakdown Voltage	V _{GE} = 0V, I _C = 250uA	1200	-	-	V
I _{CES}	Collector-Emitter Leakage Current	V _{CE} = 1200V, V _{GE} = 0V	-	-	250	uA
ı	Gate Leakage Current, Forward	V_{GE} =30V, V_{CE} = 0V	-	-	100	nA
I _{GES}	Gate Leakage Current, Reverse	V_{GE} = -30V, V_{CE} = 0V	-	-	-100	nA
$V_{\text{GE(th)}}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 250uA$	4.5	5.0	5.5	V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	V _{GE} =15V, I _C = 40A	-	2.0	2.3	V
Qg	Total Gate Charge	V _{CC} =960V	-	195		nC
Qge	Gate-Emitter Charge	V _{GE} =15V	-	90		nC
Qgc	Gate-Collector Charge	I _C =40A	_	105		nC
t _{d(on)}	Turn-on Delay Time	V _{CC} =600V	-	40	-	ns
t _r	Turn-on Rise Time		-	58	-	ns
t _{d(off)}	Turn-off Delay Time	V _{GE} =15V	-	480	-	ns
t f	Turn-off Fall Time	I_{C} =40A R_{G} =28 Ω	_	240	-	ns
Eon	Turn-on Switching Loss	Inductive	_	2.3	-	mJ
Eoff	Turn-off Switching Loss	Load T _C =25 ℃	-	3.6	-	mJ
Ets	Total Switching Loss		_	5.9	-	mJ
Cies	Input Capacitance	V _{CE} =25V	-	3000	_	pF
Coes	Output Capacitance	V _{GE} =0V	-	405	-	pF
C _{res}	Reverse Transfer Capacitance	f = 1MHz	-	230	-	pF
R _{Gint}	Integrated gate resistor	f=1M;Vpp=1V		2.5		Ω

Electrical Characteristics of Diode (TC=25°C unless otherwise noted)

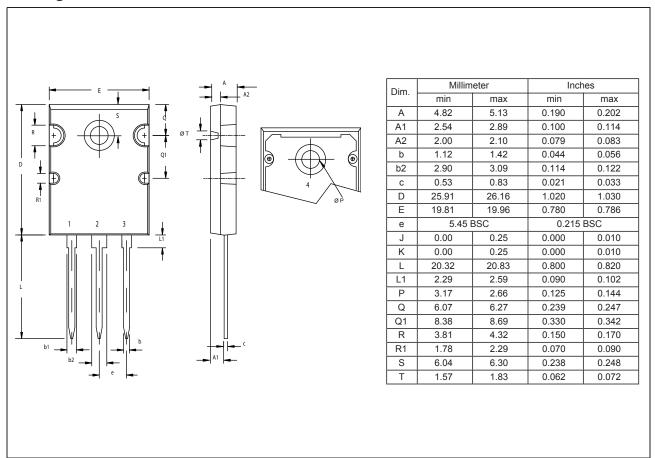
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
V_{F}	Diode Forward Voltage	I _F =40A	-	2.8	3.2	V
trr	Diode Reverse Recovery Time	V _{CE} = 600V	-	80		ns
Irr	Diode peak Reverse Recovery Current	I _F = 40A	-	18.5	-	Α
Q_{rr}	Diode Reverse Recovery Charge	dl _F /dt = 500A/us	-	690	-	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature



Package Dimensions



Ordering information

Order code	Package	Packaging option	Base quantity	Packaging specification
CXG40N120JK	TO-264	Tube/BOX	20pcs / Tube	

Revision history

Date	Revision	Changes
23-May-2012	1.0	Initial release



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